

Zeitschrift für Anorganische und Allgemeine Chemie

Cu₇Bi₆S₁₀Cl₅ – Mobile Copper(I) Cations Inside Dendritic Channels of a Rigid Framework

Journal:	Zeitschrift für Anorganische und Allgemeine Chemie
Manuscript ID:	zaac.201000040
Wiley - Manuscript type:	Article
Date Submitted by the Author:	20-Jan-2010
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Keywords:	Bismuth, Cation mobility, Copper, Covalent polyhedra networks, One-dimensional ionic conductors



Cu₇Bi₆S₁₀Cl₅ – Mobile Copper(I) Cations Inside Dendritic Channels of a Rigid Framework

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Dedicated to Professor Bernd Harbrecht on the Occation of his 60th Birthday

Keywords: Bismuth; Cation mobility; Copper; Covalent polyhedra networks; One-dimensional

ionic conductors

Running title: Mobile Cu cations in dendritic channels

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Abstract. The melting reaction of Cu, CuCl, S, and Bi₂S₃ yields black, shiny needles of the sulfide chloride Cu₇Bi₆S₁₀Cl₅. The compound decomposes peritectically above 639(5) K. Cu-*K*-XANES data confirm the oxidation state +I of Cu. Cu₇Bi₆S₁₀Cl₅ crystallizes in the monoclinic space group C2/m with a = 2878.3(9) pm, b = 396.59(9) pm, c = 1156.5(4) pm, and $\beta = 111.55(3)^{\circ}$ at T = 293(2) K. Three S and four Cl anions coordinate each of the three independent Bi cations in the shape of mono-capped trigonal prisms. The [BiS₃Cl₄] polyhedra share edges and faces resulting in furrowed layers parallel ($\overline{2}$ 01). Localized as well as disordered Cu cations occupy trigonal or tetrahedral voids in the packing of anions. The Joint Probability Density Function (JPDF) reveals branched and unbranched continuous pathways along [010], which are available for cation conduction.

Introduction

Argyrodites like Ag_7GeSe_5I [1], Cu_6PS_5X (X = Cl, Br, I) [2], and Li_6PS_5I [3] are famous for their high isotropic ionic conductivity. The three-dimensional arrangement of interconnected conduction paths in their structures is an essential prerequisite for this property. On the other hand, for electrode applications it could be desirable to find anisotropic ionic conductors, which offer electronic transport as well (mixed conductors). Quaternary phases of the systems M/Bi/Q/X (M = Cu, Ag, Q =S, Se, and X = Cl, Br, I) have been shown to be tunable small-gap semi-conductors [4], which especially in the case of the Cu compounds show also ion mobility. Typically, their structures consist of rigid substructures of $[BiQ_nX_m]$ polyhedra with disordered Cu^I in between. For example, Cu₃Bi₂S₄Cl [5] or Cu₃Bi₂S₃I₃ [6] are considered to be mixed conductors, where the different phenomena are not unidirectional. Our aim was to reveal a greater range to such highly anisotropic materials, as already successful reported in previous work [7]. Here, we present a new quaternary compound in the system Cu/Bi/S/Cl, which exhibits a rigid bismuth-anion network and inherent disordered Cu^I cations.

Experimental Section

Synthesis

A successful synthesis of Cu₇Bi₆S₁₀Cl₅ was achieved using stoichiometric amounts of Bi₂S₃ (Alfa Aesar; 99.9 %), Cu (Chemapol; p. a.), S (Laborchemie Apolda; purified and distilled), and CuCl, which had been synthesized from CuSO₄·5H₂O (Grüssing; p. a.) and NaCl (VWR; p. a.) according to *Kramb* [8]. The starting materials were handled in an Argon filled glove box (M. Braun; $c(O_2) \le 1$ ppm; $c(H_2O) \le 1$ ppm). The reaction was carried out in evacuated ($p \approx 0.1$ Pa) silica ampoules (150 mm in length, 15 mm inner diameter) placed in the middle of a tubular furnace. The educts were heated from ambient temperature to 670 K within 24 hours, cooled to 570 K in the same period of time, and tempered at 570 K for two weeks before quenching in water. The product

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consisted of hedgehogs of black needles, which exhibit metallic luster exposed to impinging light. The compound is inert against water and alcoholic solvents, but decomposes in inorganic acids.

Thermal Analysis

A powdered sample of Cu₇Bi₆S₁₀Cl₅ ($m \approx 30$ mg) enclosed in an evacuated ($p \approx 0.1$ Pa) silica micro-ampoule was analyzed using a DTA-DSC device (Labsys DSC 12, Setaram). With a rate of $\Delta T/t = 5$ K/min the sample was heated to 770 K and subsequently cooled to ambient temperature. The residua of the thermal analysis were characterized by X-ray powder diffraction.

Spectroscopic Investigation

X-ray absorption near edge spectroscopy was applied to determine the valence of the Cu ions in the material. It was performed at the Doris ring at HASYLAB of DESY in Hamburg. The examination took place at the beam line E4 at the Cu-K-edge between 8729 eV and 9977 eV with a step width of 2.4 eV.

Crystallographic Structure Determination

Cu₇Bi₆S₁₀Cl₅ was characterized by powder and single-crystal X-ray diffraction methods. Precession photographs of a single-crystal showed a monoclinic pattern with reflection conditions that led to the space groups *C*2/*m* or *Cm*. The lattice constants at 293(2) K were determined from 52 single indexed reflections of a Guinier photograph with silicon as internal standard: *a* = 2878.3(9) pm, *b* = 396.59(9) pm, *c* = 1156.5(4) pm, and β = 111.55(3) °. The reflection intensities were measured on a four-circle diffractometer with scintillation detector (AED2, Siemens/Stoe) using the learnt-profilemethod [9]. An analytical absorption correction was applied [10] based on a microscopic crystal description that had been optimized using seven ψ -scans [11]. Experimental details are summarized in Table 1. The crystal structure was solved by direct methods in the space group *C*2/*m* (no. 12) and refined against *F*² [12]. During the first steps of the structure solution three Bi, one Cu, five S and

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three Cl positions were found. The differentiation between S and Cl ions was possible by bondlength bond-strength considerations [13]. Anisotropic displacement parameters were determined for these atoms. Difference Fourier maps showed numerous maxima, which could be assigned to partially occupied Cu positions. Those significant within the bias in the Fourier map were included in the refinement procedure. First the sum of occupancies for all disordered Cu atoms was fixed based on charge balance and the assumption of the Cu oxidation state +I. As it turned out that the sum of occupancies of the positions Cu2x approximates three atoms per unit cell, it was constrained to that value. Likewise the sums of occupancies of the positions Cu_{3x} and Cu_{4x} were constrained to four and three. For disordered Cu atoms of the same group the identical isotropic displacement parameter was applied. The crystal structure refinement converged without significant residual electron densities at reliability indexes $R_1 = 0.021$ for 1735 $F_0 > 4\sigma(F_0)$ and $wR_2 = 0.046$ for all 2048 data (Table 1). Atomic parameters and selected interatomic distances are listed in Tables 2 and 3. Further details of the crystal structure determination are available from the Fachinformationszentrum Karlsruhe, D-76344 Eggenstein-Leopoldshafen (Germany), E-mail crysdata@fiz-karlsruhe.de, on quoting the depository number CSD-421386. For graphical representation of the crystal structure the program Diamond [14] was used.

The calculation of the Joint Probability Density Function (JPDF) was done with JANA [15], followed by a visualization with VESTA [16]. The Cu2 string was fitted by applying anharmonic terms of third order to a Cu atom in 0.247(1), 0.14(2), 0.514(3). For the Cu4 string a Cu atom in 0.502(2), 0.260(3), -0.002(8) was refined with a fourth order tensor. Since no large negative electron density arose in both cases, the anharmonic refinement can be regarded as an adequate description [17].

$\begin{smallmatrix} 3&4&5&6&7&8&9\\ 1&1&1&1&1&1&1&1\\ 1&1&1&2&2&2&2&2&2&2&2&2&2&3\\ 0&3&1&2&3&3&3&3&3&3&3&4&4&4&4&4&4&4&4&4&5&5&5&5$	2 2
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$\begin{array}{c} 19\\ 20\\ 21\\ 22\\ 24\\ 26\\ 27\\ 29\\ 30\\ 33\\ 33\\ 35\\ 37\\ 39\\ 41\\ 43\\ 44\\ 56\\ 78\\ 90\\ 12\\ 33\\ 45\\ 67\\ 89\\ 01\\ 12\\ 38\\ 90\\ 14\\ 23\\ 44\\ 56\\ 78\\ 90\\ 10\\ 12\\ 10\\ 10\\ 10\\ 10\\ 10\\ 10\\ 10\\ 10\\ 10\\ 10$	8
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I. Crystallographic data and details of the structure determination for Cu ₇ Bi ₆ S ₁₀ Cl ₅ .
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Compound	$Cu_7Bi_6S_{10}Cl_5$
Measuring temperature	293(2) K
Crystal system	monoclinic
Space group	<i>C</i> 2/ <i>m</i> (no. 12)
Lattice parameters	a = 2878.3(9) pm b = 396.59(9) pm c = 1156.5(4) pm $\beta = 111.55(3)^{\circ}$ $V = 1227.9(6) \times 10^{6} \text{ pm}^{3}$
Ζ	2
$\rho_{\rm calc.} \times {\rm cm}^3 / {\rm g}$	5.94
Crystal size / mm ³	$0.78 \times 0.04 \times 0.02$
Measuring system	four-circle diffractometer AED2 (Siemens/Stoe) with scintillation detector and graphite monochromator
Radiation	Mo- $K\alpha$, $\lambda = 71.073$ pm
Measuring range	$2\theta \le 60^{\circ}$ $-40 \le h \le 40$ $-5 \le k \le 5$ $-16 \le l \le 16$
Absorption correction	analytical [10]; crystal description optimized using seven ψ -scans [11]
μ (Mo- $K\alpha$) × mm	50.1
Transmission factors	0.20 to 0.30
Measured reflections	6958
Unique reflections	2048
$R_{\rm int}$	0.028
R_{σ}	0.024
Structure refinement	Least squares method; full matrix; based on F^2
Extinction parameter	$13.9(4) \times 10^{-4}$
Parameters; Restrictions	120; 3
Residual electron density $\Delta \rho \times 10^6 \text{ pm}^3 / \text{ e}$	+1.6 to -1.3
$R_{1} (all F_{o})$ $R_{1} (F_{o} > 4\sigma(F_{o}))$ $wR_{2} (all F_{o}^{2})$ Goof	0.031 0.021 0.046 1.014

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Table	2.	Wyckoff	positions,	coordinates,	occupancy	factors	(<i>k</i>)	and	equivalent	isotropic
displac	eme	ent paramet	ters of the a	toms in Cu ₇ B	$i_6S_{10}Cl_5$ at 29	93 K. U _{ec}	l (in	pm ²)	is defined as	one third
of the t	race	of the orth	nogonalized	l tensor U_{ij} .						

Atom	Position	x	у	Z.	k	$U_{ m eq},U_{ m iso}$
Bi1	4i	0.26976(1)	1/2	0.21694(3)	1	152.7(7)
Bi2	4i	0.40926(1)	0	0.46296(2)	1	141.3(7)
Bi3	4i	0.39384(1)	0	0.04258(2)	1	140.1(7)
Cu1	4i	0.15687(4)	0	0.2914(1)	1	277(2)
Cu2a	4i	0.247(1)	0	0.466(2)	0.099(7)	221(9)
Cu2b	8 <i>j</i>	0.2566(6)	0.104(6)	0.478(1)	0.135(7)	$U_{\rm iso}({\rm Cu2a}$
Cu2c	8 <i>j</i>	0.2482(6)	0.185(5)	0.488(1)	0.104(4)	$U_{\rm iso}({\rm Cu2a}$
Cu2d	8 <i>j</i>	0.2371(7)	0.286(7)	0.506(1)	0.086(8)	$U_{\rm iso}({\rm Cu2a}$
Cu3a	4i	0.5348(7)	1/2	0.190(2)	0.055(2)	174(4)
Cu3b	4i	0.5240(5)	1/2	0.231(2)	0.25(1)	$U_{\rm iso}({\rm Cu3a})$
Cu3c	4i	0.5179(4)	1/2	0.260(2)	0.452(3)	$U_{\rm iso}({\rm Cu3a})$
Cu3d	4i	0.5125(4)	1/2	0.288(2)	0.29(1)	$U_{\rm iso}({\rm Cu3a})$
Cu3e	4i	0.473(1)	1/2	0.282(3)	0.030(1)	$U_{\rm iso}({\rm Cu3a})$
Cu4a	2a	1/2	1/2	0	0.090(2)	268(10)
Cu4b	8 <i>j</i>	0.5054(5)	0.411(3)	0.046(2)	0.062(3)	$U_{\rm iso}({\rm Cu4a}$
Cu4c	4g	1/2	0.313(2)	0	0.219(2)	$U_{\rm iso}({\rm Cu4a}$
Cu4d	8 <i>j</i>	0.5087(3)	0.158(2)	0.0189(7)	0.118(2)	$U_{\rm iso}({\rm Cu4a}$
Cu4e	4i	0.513(3)	0	0.022(6)	0.041(7)	$U_{\rm iso}({\rm Cu4a}$
Cu4f	2b	1/2	0	0	0.171(2)	$U_{\rm iso}({\rm Cu4a}$
S 1	4i	0.20309(7)	1/2	0.3203(2)	1	160(3)
S2	4i	0.31045(6)	0	0.3805(2)	1	150(3)
S 3	4i	0.40060(6)	1/2	0.6074(2)	1	130(3)
S4	4i	0.48737(6)	0	0.1760(2)	1	163(3)
S5	4i	0.41240(7)	1/2	-0.0877(2)	1	146(3)
Cl1	4i	0.20722(6)	0	0.0500(2)	1	175(3)
Cl2	4i	0.38504(7)	0	0.2433(2)	1	187(3)
Cl3	2c	1/2	1⁄2	1/2	1	266(6)

 Table 3. Selected interatomic distances (in pm) for $Cu_7Bi_6S_{10}Cl_5$. Symmetry operators: (*i*): *x*, *y*, *z*; (*ii*): *x*, *y*+1, *z*; (*iii*): 1/2–*x*, 1/2–*y*, –*z*; (*iv*): *x*, *y*–1, *z*; (*v*): 1/2–*x*, –*y*–1/2, –*z*; (*vi*): 1/2–*x*, 1/2–*y*, 1–*z*; (*vii*): 1–*x*, 1–*y*, 1–*z*; (*viii*): 1–*x*, 1–*y*, –*z*; (*ix*): 1–*x*, –*y*, –*z*.

Bi1-	S 1	260.7(2)	Cu2a–	$S1^{vi}$	236(2)	Cu3a–	$S5^{viii}$	225(3)	Cu4a–	S5 ^{i, viii}	234.7(2)
	S2 ^{i, ii}	269.3(1)		S2	238(2)		$S4^{i,ii}$	238(1)		$S4^{i,ii,viiiix}$	295.8(2)
	Cl1 ^{i, ii}	288.9(2)		$S1^{i,iv}$	260(1)		$S3^{vi}$	239(2)			
	Cl2	321.9(2)							Cu4b-	$S5^{viii}$	226(1)
	Cl1 ⁱⁱⁱ	338.8(2)	Cu2b-	$S1^{vi}$	222.6(9)	Cu3b-	$S4^{i,ii}$	222.7(3)		S4	240(1)
				S2	227(1)		$S3^{vii}$	228.3(5)		S5	258(1)
Bi2–	S2	264.7(2)		S 1	247(1)		$S5^{ m viii}$	289(3)		S4 ⁱⁱ	292(1)
	$S3^{i,iv}$	266.3(1)									
	$Cl2^{i,iv}$	309.4(2)	Cu2c-	$S1^{i,vi}$	227(1)	Cu3c-	$S4^{i,ii}$	224.0(4)	Cu4c-	$S5^{i, viii}$	246.2(3)
	$Cl3^{i,iv}$	318.04(7)		S2	263(2)		$S3^{vii}$	228.3(4)		S4 ^{i, ix}	252.1(5)
				$S2^{vi}$	294(2)						
Bi3–	S4	256.5(2)				Cu3d-	$S4^{i,ii}$	233.3(9)	Cu4d-	S4	221.1(9)
	$S5^{i,iv}$	266.1(1)	Cu2d-	S 1	218(1)		$S3^{vii}$	234.4(8)		S4 ^{ix}	238.3(8)
	Cl2 ^{i, iv}	313.3(2)		$S2^{vi}$	237(2)		C13	261(3)		$S5^{viii}$	251.1(7)
	$\text{Cl1}^{\text{iii, v}}$	335.4(2)		$S1^{vi}$	240(1)					S5	292.0(8)
						Cu3e-	Cl3	235(3)			
Cu1-	S1 ^{i, iv}	234.3(1)					Cl2	240(3)	Cu4e-	S4	215(3)
	S3 ^{vi}	235.1(2)					$S4^{i,ii}$	245(2)		S4 ^{ix}	229(4)
	S5 ⁱⁱⁱ	246.5(2)								S5 ^{viii, ix}	282(6)
									Cu4f-	S4 ^{i, ix}	219.5(2)

Results and Discussion

The thermal reaction of Cu, CuCl, S and Bi_2S_3 resulted in shiny black needles of the sulfide chloride Cu₇Bi₆S₁₀Cl₅. With respect to the pseudo-ternary phase diagram the sum formula can be rearranged as $5BiSCl^{-1}/_2Bi_2S_3$. Heating Cu₇Bi₆S₁₀Cl₅ in evacuated silica ampoules results in peritectoid decomposition at 639(5) K. After slow cooling to ambient temperature, Cu₃Bi₂S₄Cl [5] as well as smaller amounts of CuBiSCl₂ [4] and BiSCl [18] were detected by X-ray powder diffractometry. The decomposition reaction can be written as

$$Cu_7Bi_6S_{10}Cl_5 \rightarrow 2Cu_3Bi_2S_4Cl + CuBiSCl_2 + BiSCl.$$

The oxidation state +I of the Cu cations was verified by XANES measurements (Fig. 1). The energy of the copper *K* edge of $Cu_7Bi_6S_{10}Cl_5$ is very similar to the reference CuCl, while there is a large difference to the position of the edge of CuS. The instability of Cu^{II} in sulfidic environment is once more demonstrated [19].

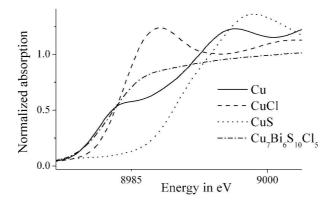


Figure 1. XANES spectrum at the Cu K edge of $Cu_7Bi_6S_{10}Cl_5$ as well as of reference substances.

The monoclinic crystal structure of $Cu_7Bi_6S_{10}Cl_5$ can be subdivided into a layered rigid backbone formed by the Bi cations and the anions, and more or less mobile Cu cations in between (Fig. 2). Each of the three independent Bi cations is coordinated by three S and four Cl anions in the shape of a mono-capped trigonal prism. Such coordination spheres of anions surrounding bismuth cations are already reported for substances like $Cu_3Bi_2S_4Cl$ [5] or $Cu_9Bi_9S_{16}Cl_8$ [7]. The [BiS₃Cl₄] polyhedra share edges and faces resulting in compact rods with six prisms in the cross section

running along [010] and eventually in corrugated layers $\frac{2}{\infty}$ [Bi₆S₁₀Cl₅]⁷⁻ parallel ($\overline{2}$ 01). The same connectivity of prisms as in the six-membered rods can also be found in the crystal structure of Cu₃Bi₂S₄Cl [5, 20], which is a thermal decomposition product of Cu₇Bi₆S₁₀Cl₅ (vide supra). The idea of an essentially rigid polyhedral substructure is supported by the astonishingly regular displacement ellipsoids of the anions, which indicate only minor response of the anions to the varying occupancies of the Cu positions. Although the anions are well localized, their polarizability allows exchange of Cu cations between neighboring sites. Every Cl anion is connected to four or five Bi cations, whereas the S anions coordinate only one to three Bi cations. In other words, the Cl anions are located inside the polyhedral framework, while the S anions form its interface to the Cu cations. Consequently the chemical surrounding of the Cu cations is dominated by S anions. The feature that the mobile Cu ions are coordinated by the more polarizable anions is known from related compounds like Cu₉Bi₉S₁₆Cl₈ [7] as well.

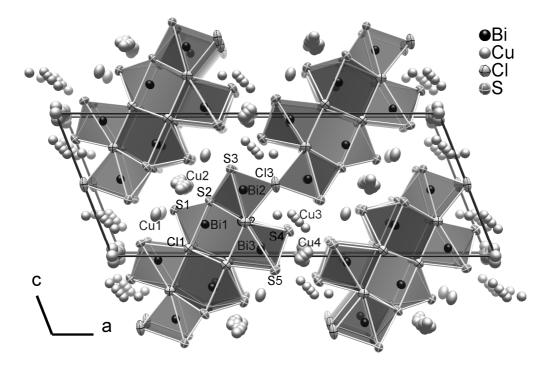


Figure 2. Crystal structure of $Cu_7Bi_6S_{10}Cl_5$ emphasizing the layers of [BiS₃Cl₄] prisms. The ellipsoids represent 95 % probability.

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The localized Cu1 atom centers a tetrahedron of S anions with d(Cu-S) = 234 - 246 pm. The next nearest Cu position, Cu2a, is 263 pm away and also coordinated tetrahedrally (Figure3). Since the two coordination polyhedra share a common edge, an exchange between the two positions seems to be unlikely. The positions Cu2a to Cu2d form an infinite sequence of closely spaced positions along [010] with no more than 50 pm between neighboring sites. This feature has been regarded as an indicator of high ion mobility and low activation energies for hopping from one position to another [21], which is a necessary condition for a good ionic conductor. An alternative representation of the electron density using the Joint Probability Density Function (JPDF) reveals a continuous pathway. The unusually high isosurface level $\eta = 0.2 \text{ e/}(10^6 \text{ pm}^3)$ of this path is a consequence of two peculiarities: Firstly, all Cu2 sites are almost equally populated, although Cu2b, Cu2c, and Cu2d are only coordinated trigonally by S. Secondly, the overall population of 1.5 Cu2 atoms per string and translational period *b*, which corresponds to an average distance of 264 pm between occupied sites, is rather high.

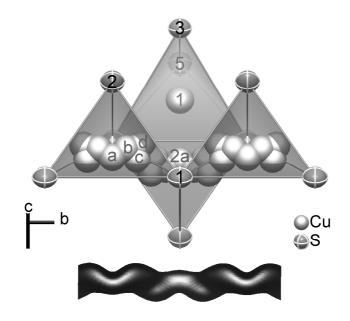


Figure 3. Localized Cu1 and disordered Cu2 cations in the crystal structure of Cu₇Bi₆S₁₀Cl₅. The tetrahedra are centered by Cu1 and Cu2a. The ellipsoids represent 95 % probability. Below: The JPDF of the Cu2 string with an isosurface of $\eta = 0.2 \text{ e}/(10^6 \text{ pm}^3)$.

The same holds for the series of Cu4 positions, which show a quite similar density of sites and the same average overall population (Fig. 4). Again the JPDF is continuous at an isosurface level of $\eta = 0.2 \text{ e/}(10^6 \text{ pm}^3)$. Cu4c is coordinated tetrahedrally, while Cu4b and Cu4d have trigonal, and Cu4a and Cu4e linear coordination of S anions. The major difference lies in the orthogonal branches of the Cu4 string formed by the sites Cu3a to Cu3e. If the string of Cu4 positions is regarded the "street" for mobile Cu cations, the Cu3 positions are the "parking". Any Cu ion entering or leaving the branch must pass through a triangle of S anions and beat the distance d(Cu3a-Cu4b) = 161 pm. Furthermore, the sum of occupancies for the Cu3 position equals one Cu atom per branch, i.e. the "parking" is occupied. Cu3a is coordinated by four, Cu3b as well as Cu3c by three S anions. Cu3d and Cu3e, lying deep in the furrows of the [Bi₀S₁₀Cl₅]^{7–} layers, occupy tetrahedral voids and hold one or two Cl anions in their coordination.

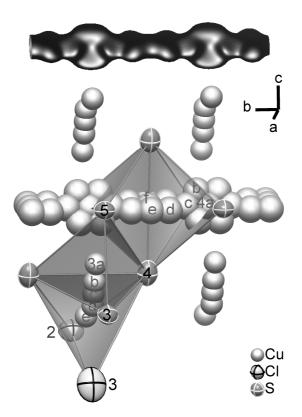


Figure 4. Disordered Cu3 and Cu4 cations forming a dentritic one-dimensional substructure in Cu₇Bi₆S₁₀Cl₅. The tetrahedra shown are centered by Cu3a, Cu3e, and Cu4c. The ellipsoids represent 95 % probability. Above: The JPDF of the Cu4 string with an isosurface of $\eta = 0.2 \text{ e}/(10^6 \text{ pm}^3)$.

Concluding Remark

On an absolute scale the ionic conductivity of $Cu_7Bi_6S_{10}Cl_5$ will not be able to compete with argyrodites like Ag_7GeSe_5I [1], Cu_6PS_5X (X = Cl, Br, I) [2], and Li_6PS_5I [3], which exhibit tremendous ionic mobility. However, the structural concept of compounds like $Cu_7Bi_6S_{10}Cl_5$ seems to be interesting for one-dimensional, i.e. structurally directed, ionic conductivity. The onedimensional character in combination with the high density of Cu cations may substantially slow down the mobility of individual cations. On the other hand, the group velocity could be acceptable, since only few steps of transport are necessary to deliver a cation at the electrode. Furthermore, back jumps should be less probable than in compounds with less Cu cations on the available sites. The cruces for any imaginable application are the needle-like habitus of the crystals and the intricate crystal growth of a compound decomposing peritectically.

Acknowledgement

We wish to thank *Rolf Heich*, *Gudrun Kadner*, and *Jutta Krug* for experimental support. *Dr. Frauke Philipp* is gratefully acknowledged for her assistance in measuring and interpreting the XANES data.

Literature

- a) R. Belin, L. Aldon, A. Zerouale, C. Belin, M. Ribes, *Solid State Sci.* 2001, *3*, 251; b) S.
 Albert, S. Pillet, C. Lecomte, A. Pradel, M. Ribes, *Acta Crystallogr.* 2008, *B64*, 1.
- [2] a) W. F. Kuhs, R. Nitsche, K. Scheunemann, Acta Crystallogr. 1978, B34, 64; b) T. Nilges,
 A. Pfitzner, Z. Kristallogr. 2005, 220, 281; c) A. Gagor, A. Pietraszko, M. Drozd, M. Połomska, Cz. Pawlaczyk D. Kaynts, J. Phys.: Condens. Matter 2006, 18, 4489; d) A. Gagor, A. Pietraszko, D. Kaynts, J. Solid State Chem. 2008, 181, 777.

- [3] H.-J. Deiseroth, S. Kong, H. Eckert, J. Vannahme, C. Reiner, T. Zaiß, M. Schlosser, Angew. Chem. 2008, 120, 767; Angew. Chem. Int. Ed. 2008, 47, 755. [4] a) M. Ruck, P. F. P. Poudeu, T. Söhnel, Z. Anorg. Allg. Chem. 2004, 630, 63; b) P. F. P. Poudeu, T. Söhnel, M. Ruck, Z. Anorg. Allg. Chem. 2004, 630, 1276; c) P. F. P. Poudeu, M. Ruck, J. Solid State Chem. 2006, 179, 3636; d) M. Ruck, P. F. P. Poudeu, Z. Anorg. Allg. Chem. 2008, 634, 475; e) M. Ruck, P. F. P. Poudeu, Z. Anorg. Allg. Chem. 2008, 634, 482. [5] J. Lewis, V. Kupčík, Acta Crystallogr. 1974, B30, 848. [6] T. Balić-Žunić, K. Mariolacos, K. Friese, E. Makovicky, Acta Crystallogr. 2005, B61, 239. A. Heerwig, M.Ruck, Z. Anorg. Allg. Chem. 2009, 635, 2162. [7] [8] V. Kramb, W. Proske, V. Wiskamp, Naturwissenschaft im Unterricht – Chemie 1996, 7, 9. [9] W. Clegg, Acta Crystallogr. 1981, A37, 22. N. W. Alcock, P. J. Marks, K.-G. Adams, modified version of the program ABSPSI (by N. [10] W. Alcock, P. J. Marks) for absorption correction of single crystal data, University of Karlsruhe, 1995.
 - [11] W. Herrendorf, program HABITUS for the optimization of the crystal description for numerical absorption correction using ψ -scans, University of Karlsruhe, 1993.
 - [12] a) G. M. Sheldrick, SHELX97, Programs for crystal structure determination, Univ.
 Göttingen 1997; b) G. M. Sheldrick, Acta Crystallogr. 2008, A64, 112.
 - [13] N. E. Brese, M. O'Keeffe, Acta Crystallogr. 1991, B47, 192.
 - [14] K. Brandenburg, *Diamond 3.2c*, *Crystal and Molecular Structure Visualization*, Crystal Impact GbR, Bonn, Germany 2009.
 - [15] a) V. Petříček, M. Dušek, L. Palatinus, *Jana2006, the crystallographic computing system*.
 Institute of Physics, Praha, Czech Republic 2009; b) V. Petříček, V., A. van der Lee, M. Evain, *Acta Crystallogr.* 1995, *A51*, 529; c) L. Palatinus, G. Chapuis, *J. Appl. Crystallogr.* 2007, 40, 786.
 - [16] K. Momma, F. Izumi, J. Appl. Crystallogr. 2008, 41, 653.

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- [17] R. Bachmann, H. Schulz, Acta Crystallogr. 1984, A40, 668.
- [18] a) E. Dönges, Z. Anorg. Allg. Chem. 1950, 263, 112; b) G. P. Voutsas, P. J. Rentzeperis, Z. Kristallogr. 1980, 152, 109.
- [19] S. W. Goh, A. N. Buckley, R. N. Lamb, *Min. Eng.* **2006**, *19*, 204.
- [20] M. Ruck, Z. Anorg. Allg. Chem. 2002, 628, 1537.
- [21] C. Langecker, K. Andoura, H.-L. Keller, T. Oldag, Z. Anorg. Allg. Chem. 2006, 632, 582.

Supplementary Material

